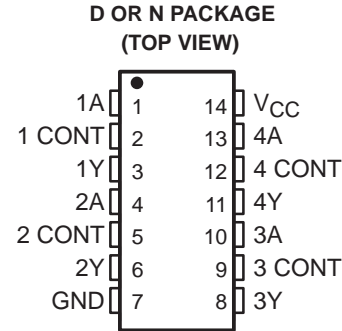


SN75C189, SN75C189A QUADRUPLE LOW-POWER LINE RECEIVERS

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- Meet or Exceed the Requirements of ANSI EIA/TIA-232-E and ITU Recommendation V.28
- Low Supply Current . . . 420 μ A Typ
- Preset On-Chip Input Noise Filter
- Built-in Input Hysteresis
- Response and Threshold Control Inputs
- Push-Pull Outputs
- Functionally Interchangeable and Pin Compatible With Texas Instruments SN75189/SN75189A, Motorola MC1489/MC1489A, and National Semiconductor DS14C88A



description

The SN75C189 and SN75C189A are low-power bipolar quadruple line receivers that are used to interface data terminal equipment (DTE) with data circuit-terminating equipment (DCE). These devices have been designed to conform with ANSI Standard EIA/TIA-232-E.

The SN75C189 has a 0.33 V typical hysteresis compared with 0.97 V for the SN75C189A. Each receiver has provision for adjustment of the overall input threshold levels. This is achieved by choosing external series resistors and voltages to provide bias levels for the response control pins. The output is in the high logic state if the input is left open circuited or shorted to ground.

These devices have an on-chip filter that rejects input pulses of shorter than 1- μ s minimum duration. An external capacitor may be connected from the control pins to ground to provide further input noise filtering for each receiver.

The SN75C189 and SN75C189A have been designed using low-power techniques in a bipolar technology. In most applications, these receivers will interface to single inputs of peripheral devices such as UARTs, ACEs, or microprocessors. By using sampling, such peripheral devices are usually insensitive to the transition times of the input signals. If this is not the case or for other uses, it is recommended that the SN75C189 and SN75C189A outputs be buffered by single Schmitt input gates or single gates of the HCMOS, ALS, or 74F logic families.

The SN75C189 and SN75C189A are characterized for operation from 0°C to 70°C.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

 **TEXAS
INSTRUMENTS**

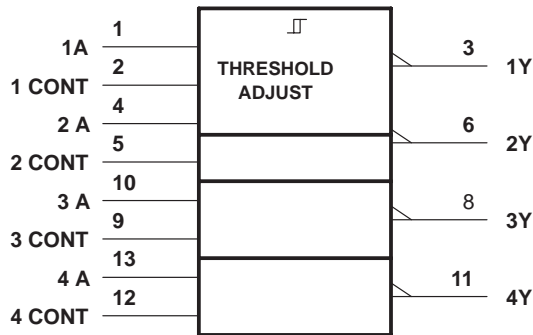
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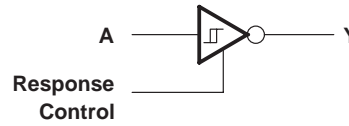
SN75C189, SN75C189A QUADRUPLE LOW-POWER LINE RECEIVERS

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logic symbol†

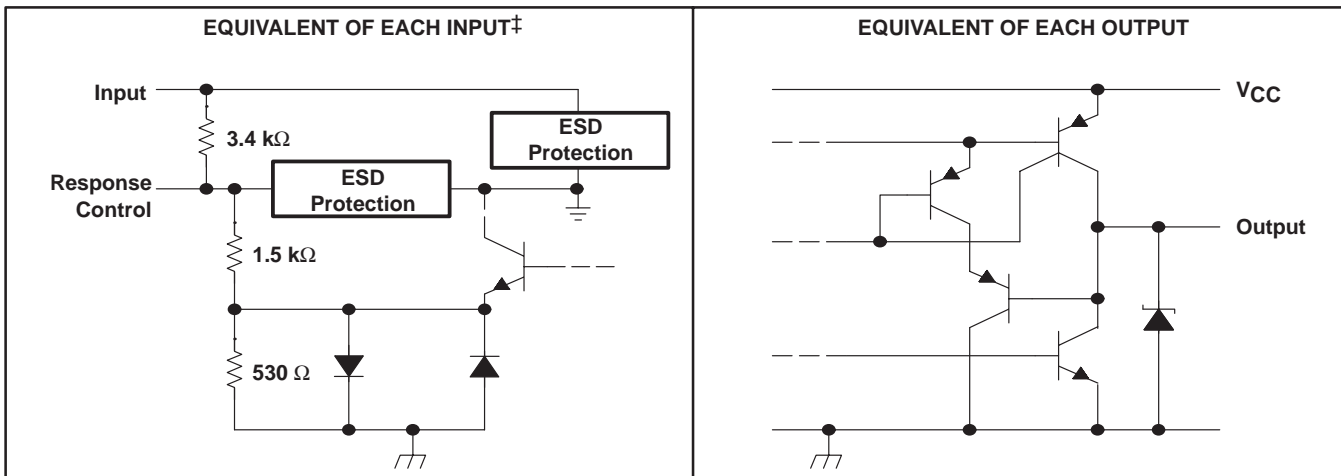


logic diagram (each receiver)



† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

schematic of inputs and outputs



‡ All resistor values shown are nominal.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)§

Supply voltage, V_{CC} (see Note 1)	7 V
Input voltage range, V_I	-30 V to 30 V
Output voltage range, V_O	-0.3 V to $V_{CC} + 0.3$ V
Continuous total dissipation	See Dissipation Rating Table
Operating free-air temperature range, T_A : SN75C189, SN75C189A	0°C to 70°C
Storage temperature range, T_{stg}	-65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

§ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: All voltages are with respect to the network ground terminal.

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DISSIPATION RATING TABLE

PACKAGE	$T_A = 25^\circ\text{C}$ POWER RATING	DERATING FACTOR ABOVE $T_A = 25^\circ\text{C}$	$T_A = 70^\circ\text{C}$ POWER RATING
D	950 mW	7.6 mW/ $^\circ\text{C}$	608 mW
DB	525 mW	4.2 mW/ $^\circ\text{C}$	336 mW
N	1150 mW	9.2 mW/ $^\circ\text{C}$	736 mW
NS	500 mW	4.0 mW/ $^\circ\text{C}$	320 mW

recommended operating conditions

	MIN	NOM	MAX	UNIT
Supply voltage, V_{CC}	4.5	5	6	V
Input voltage, V_I (see Note 2)	-25		25	V
High-level output current, I_{OH}			-3.2	mA
Low-level output current, I_{OL}			3.2	mA
Response control current			± 1	mA
Operating free-air temperature, T_A	0		70	$^\circ\text{C}$

NOTE 2: The algebraic convention, where the more positive (less negative) limit is designated as maximum, is used in this data sheet for logic levels only, e.g., if -10 V is a maximum, the typical value is a more negative voltage.

electrical characteristics over recommended free-air temperature range, $V_{CC} = 5\text{ V} \pm 10\%$ (unless otherwise noted) (see Note 3)

PARAMETER		TEST CONDITIONS	MIN	TYP†	MAX	UNIT	
V_{IT+}	Positive-going input threshold voltage	See Figure 1		1	1.5	V	
					1.6		2.25
V_{IT-}	Negative-going input threshold voltage	See Figure 1		0.75	1.25	V	
				0.75	1		1.25
V_{hys}	Input hysteresis voltage ($V_{IT+} - V_{IT-}$)	See Figure 1		0.15	0.33	V	
				0.65	0.97		
V_{OH}	High-level output voltage	$V_{CC} = 4.5\text{ V to }6\text{ V}, V_I = 0.75\text{ V}, I_{OH} = -20\ \mu\text{A}$		3.5		V	
				$V_{CC} = 4.5\text{ V to }6\text{ V}, V_I = 0.75\text{ V}, I_{OH} = -3.2\text{ mA}$	2.5		
V_{OL}	Low-level output voltage	$V_{CC} = 4.5\text{ V to }6\text{ V}, V_I = 3\text{ V}, I_{OL} = 3.2\text{ mA}$			0.4	V	
I_{IH}	High-level input current	See Figure 2		$V_I = 25\text{ V}$	3.6	8.3	mA
				$V_I = 3\text{ V}$	0.43	1	
I_{IL}	Low-level input current	See Figure 2		$V_I = -25\text{ V}$	-3.6	-8.3	mA
				$V_I = -3\text{ V}$	-0.43	-1	
I_{OS}	Short-circuit output current	See Figure 3			-35	mA	
I_{CC}	Supply current	$V_I = 5\text{ V},$ See Figure 2	No load,		420	700	μA

† All typical values are at $T_A = 25^\circ\text{C}$.

NOTE 3: All characteristics are measured with response control terminal open.



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switching characteristics, $V_{CC} = 5\text{ V} \pm 10\%$, $T_A = 25^\circ\text{C}$

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t_{PLH} Propagation delay time, low- to high-level output	$R_L = 5\text{ k}\Omega$, $C_L = 50\text{ pF}$, See Figure 4			6	μs
t_{PHL} Propagation delay time, high- to low-level output				6	μs
t_{TLH} Transition time, low- to high-level output [†]				500	ns
t_{THL} Transition time, high- to low-level output [†]				300	ns
$t_{W(N)}$ Duration of longest pulse rejected as noise [‡]			1		6

[†] Measured between 10% and 90% points of output waveform.

[‡] The receiver ignores any positive- or negative-going pulse that is less than the minimum value of $t_{W(N)}$ and accepts any positive- or negative-going pulse greater than the maximum of $t_{W(N)}$.



PARAMETER MEASUREMENT INFORMATION†

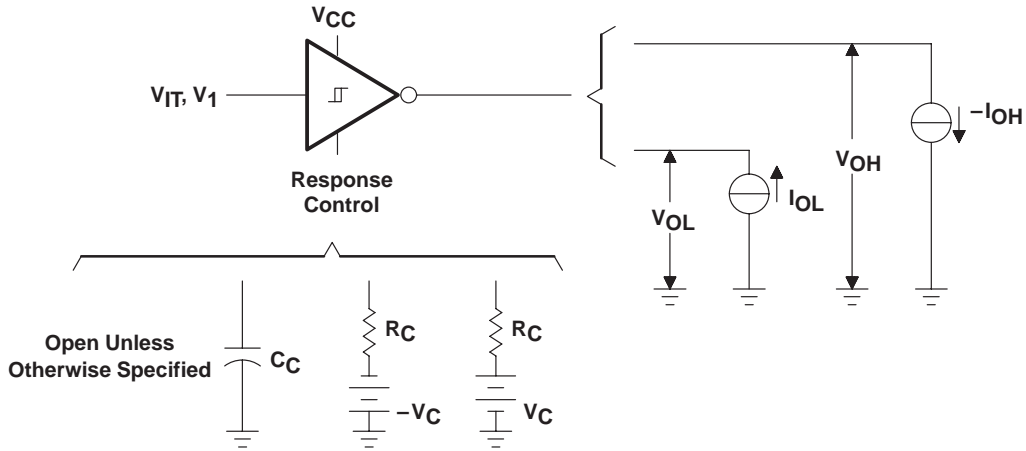


Figure 1. V_{T+} , V_{IT-} , V_{OH} , V_{OL}

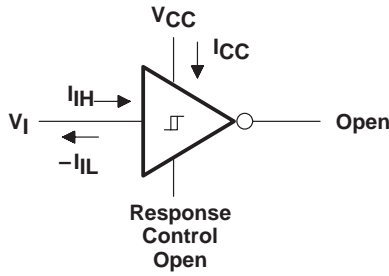


Figure 2. I_{IH} , I_{IL} , I_{CC}

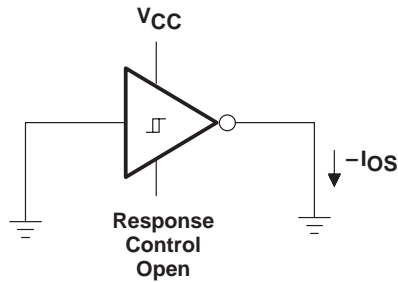


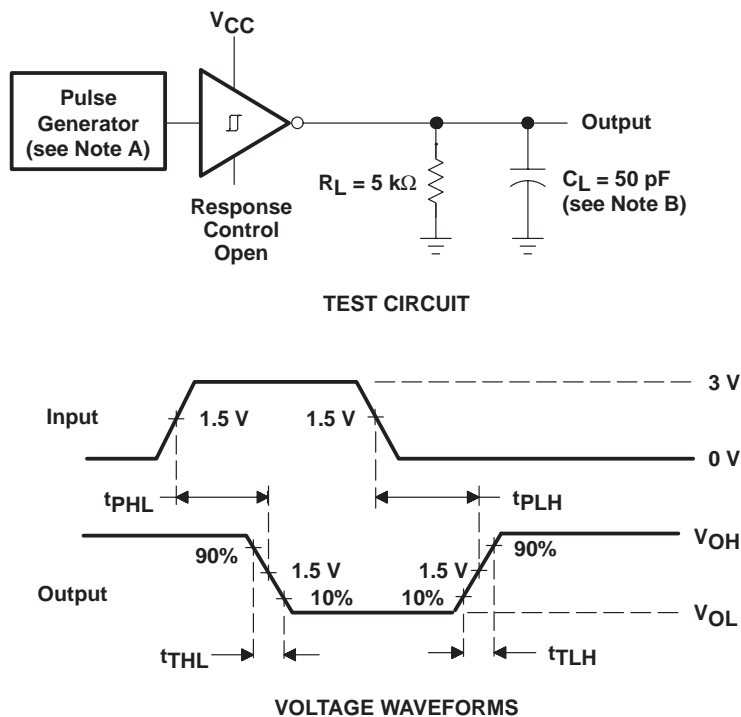
Figure 3. I_{OS}

† Arrows indicate actual direction of current flow. Current into a terminal is a positive value.

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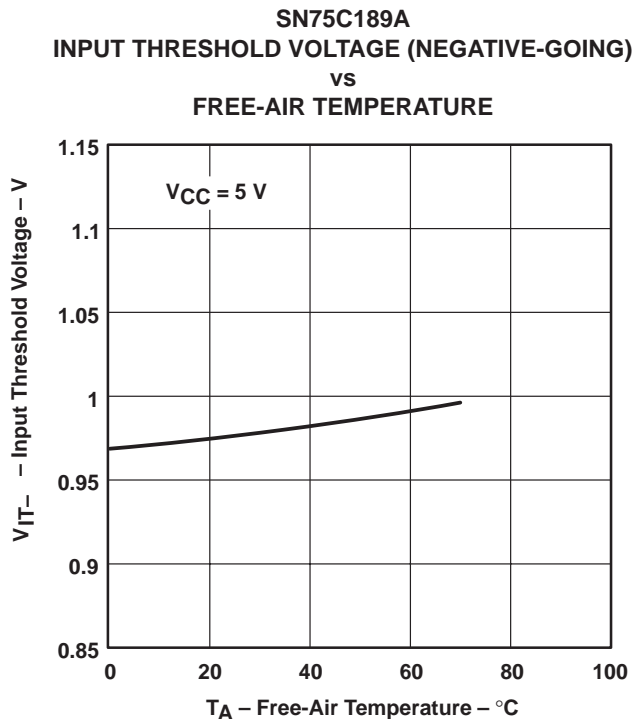
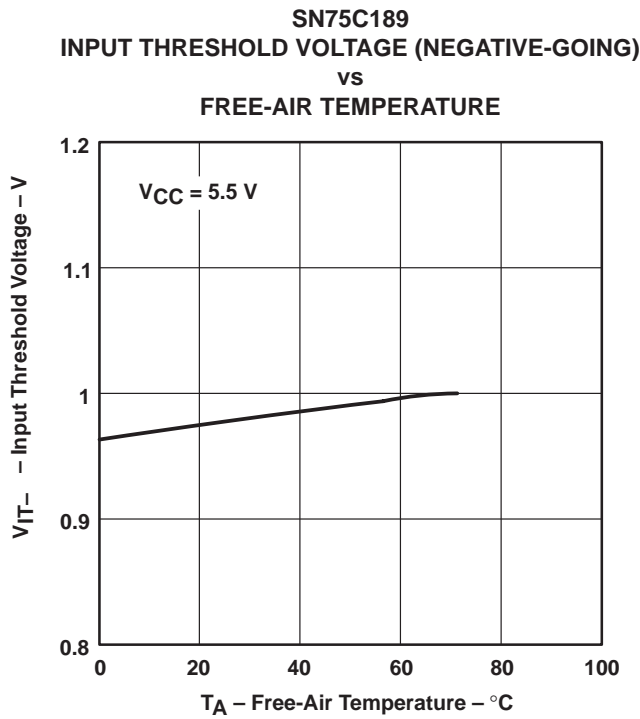
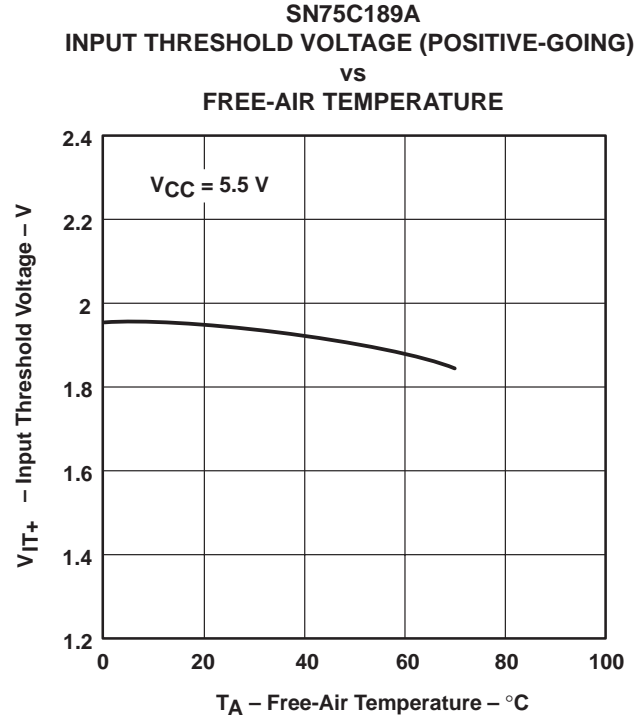
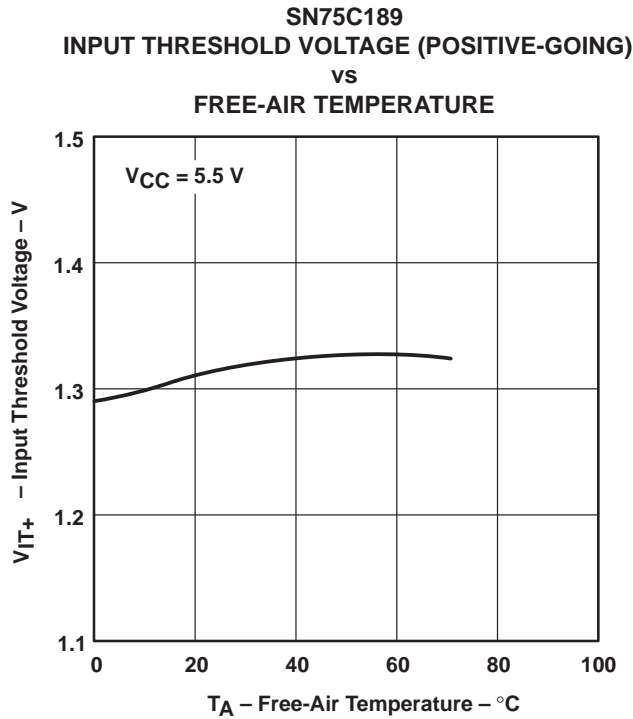
PARAMETER MEASUREMENT INFORMATION



NOTES: A. The pulse generator has the following characteristics: $Z_O = 50\ \Omega$, $t_W = 25\ \mu\text{s}$.
 B. C_L includes probe and jig capacitances.

Figure 4. Test Circuit and Voltage Waveforms

TYPICAL CHARACTERISTICS



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TYPICAL CHARACTERISTICS

**SN75C189
INPUT HYSTERESIS
vs
FREE-AIR TEMPERATURE**

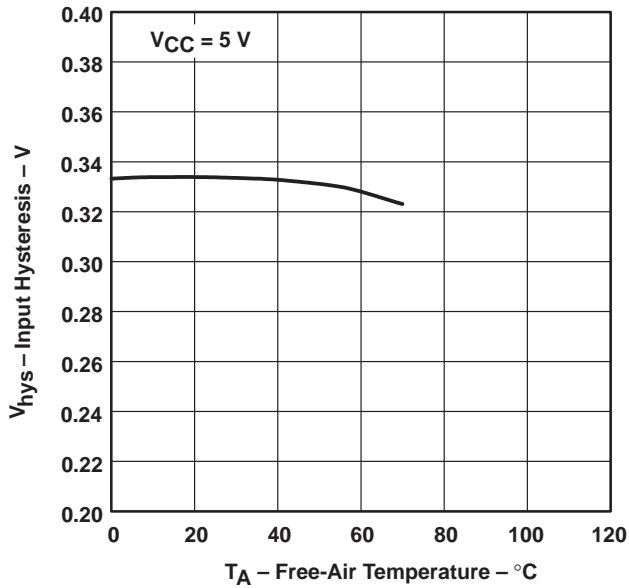


Figure 9

**SN75C189A
INPUT HYSTERESIS
vs
FREE-AIR TEMPERATURE**

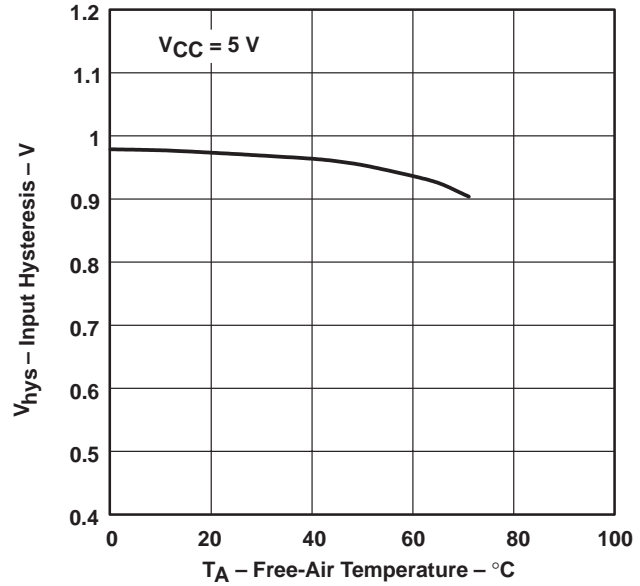


Figure 10

**HIGH-LEVEL OUTPUT VOLTAGE
vs
FREE-AIR TEMPERATURE**

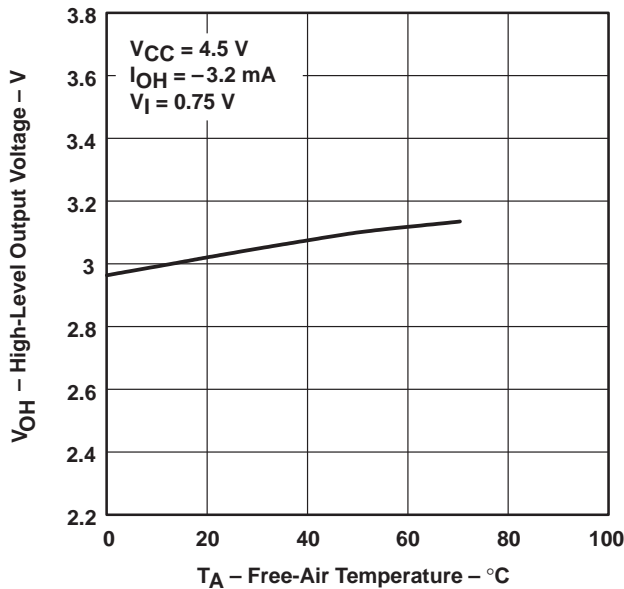


Figure 11

**LOW-LEVEL OUTPUT VOLTAGE
vs
FREE-AIR TEMPERATURE**

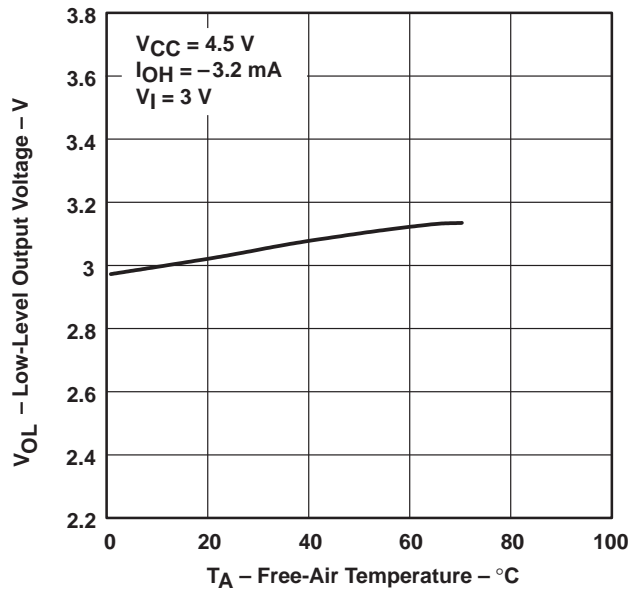


Figure 12



TYPICAL CHARACTERISTICS

SN75C189
 HIGH-LEVEL INPUT CURRENT
 vs
 FREE-AIR TEMPERATURE

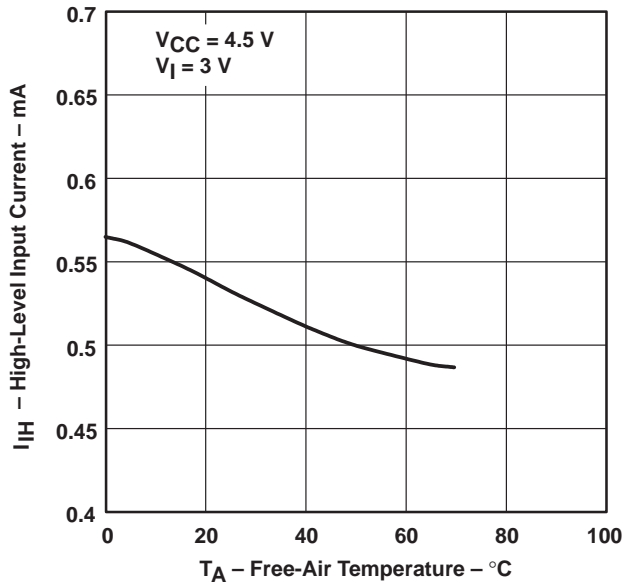


Figure 13

SN75C189A
 HIGH-LEVEL INPUT CURRENT
 vs
 FREE-AIR TEMPERATURE

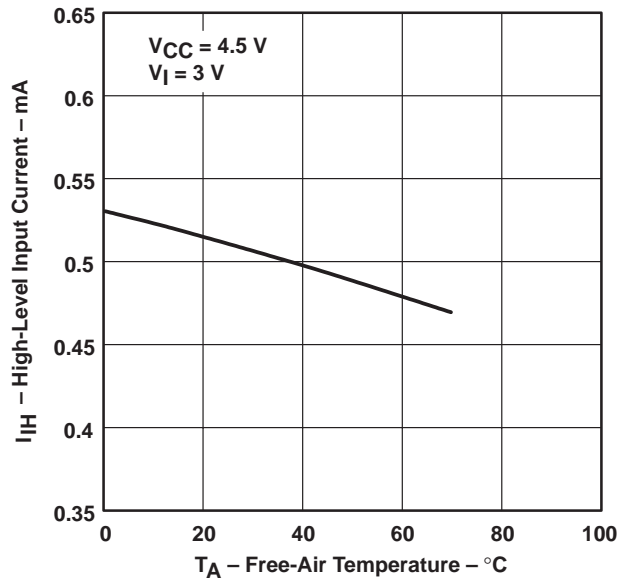


Figure 14

SN75C189
 LOW-LEVEL INPUT CURRENT
 vs
 FREE-AIR TEMPERATURE

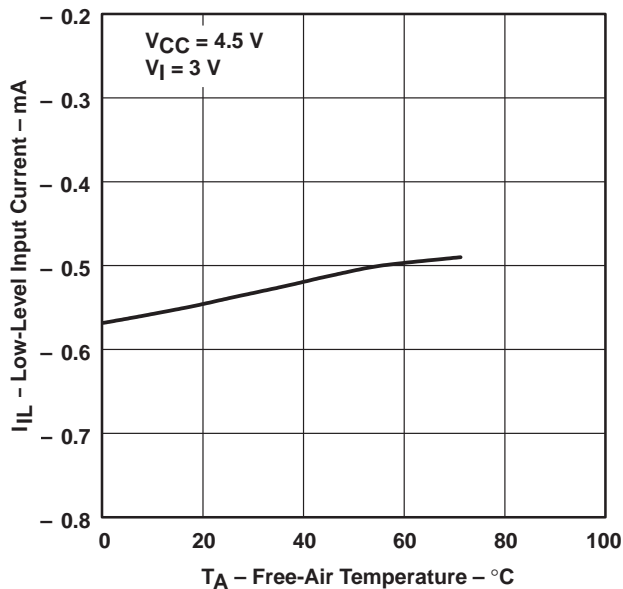


Figure 15

SN75C189A
 LOW-LEVEL INPUT CURRENT
 vs
 FREE-AIR TEMPERATURE

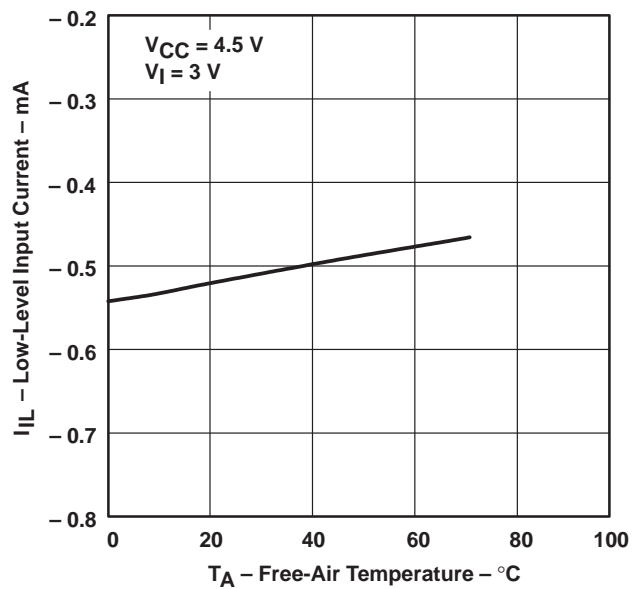


Figure 16

SN75C189, SN75C189A QUADRUPLE LOW-POWER LINE RECEIVERS

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TYPICAL CHARACTERISTICS

HIGH-LEVEL SHORT-CIRCUIT OUTPUT CURRENT
vs
FREE-AIR TEMPERATURE

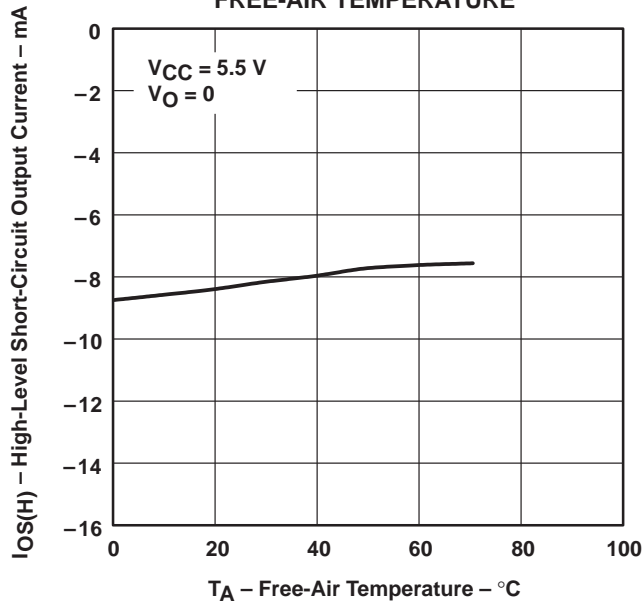


Figure 17

LOW-LEVEL SHORT-CIRCUIT OUTPUT CURRENT
vs
FREE-AIR TEMPERATURE

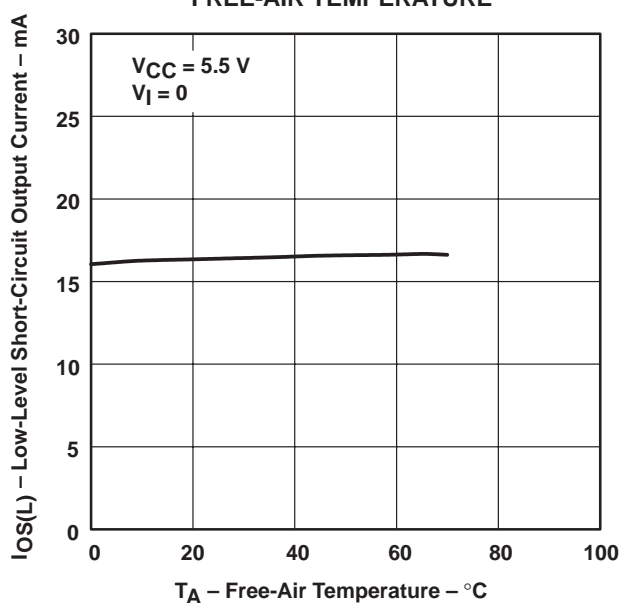


Figure 18

SUPPLY CURRENT
vs
FREE-AIR TEMPERATURE

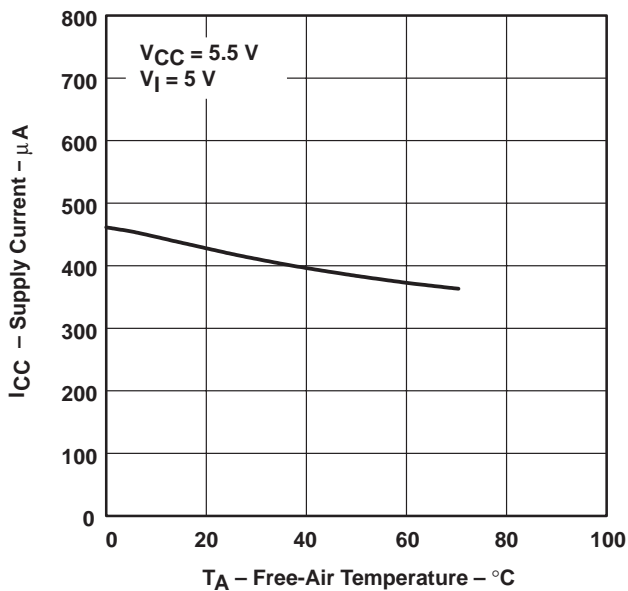


Figure 19

PROPAGATION DELAY TIME,
LOW-TO-HIGH LEVEL OUTPUT
vs
FREE-AIR TEMPERATURE

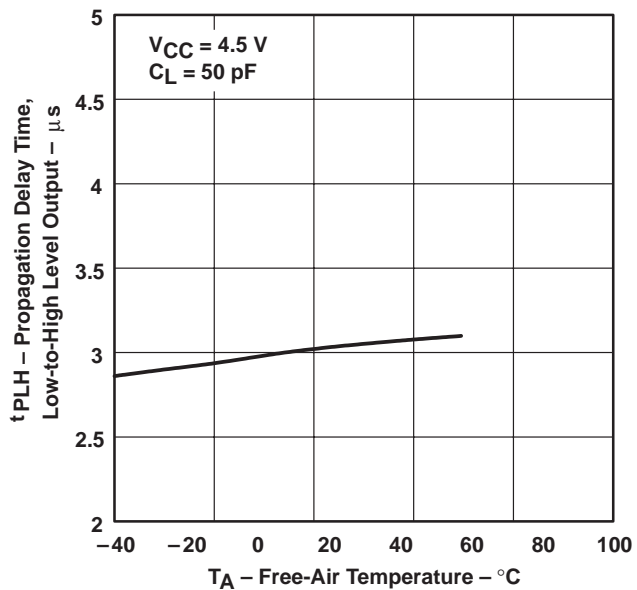


Figure 20



TYPICAL CHARACTERISTICS

PROPAGATION DELAY TIME,
 HIGH-TO-LOW-LEVEL OUTPUT
 vs
 FREE-AIR TEMPERATURE

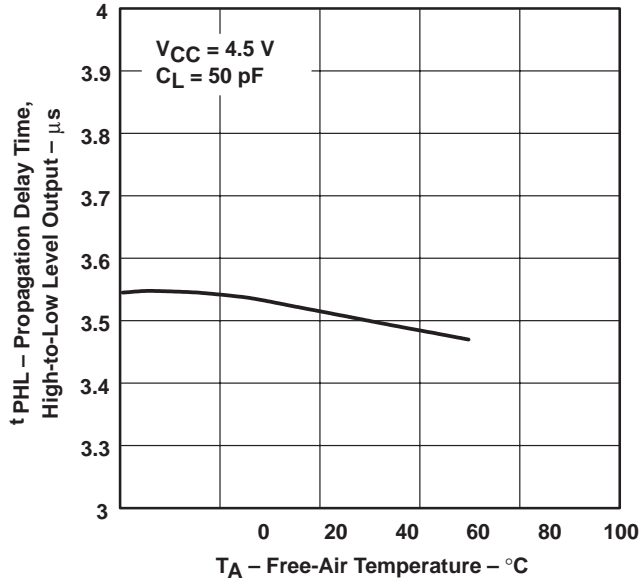


Figure 21

TRANSITION TIME,
 LOW-TO-HIGH-LEVEL
 vs
 FREE-AIR TEMPERATURE

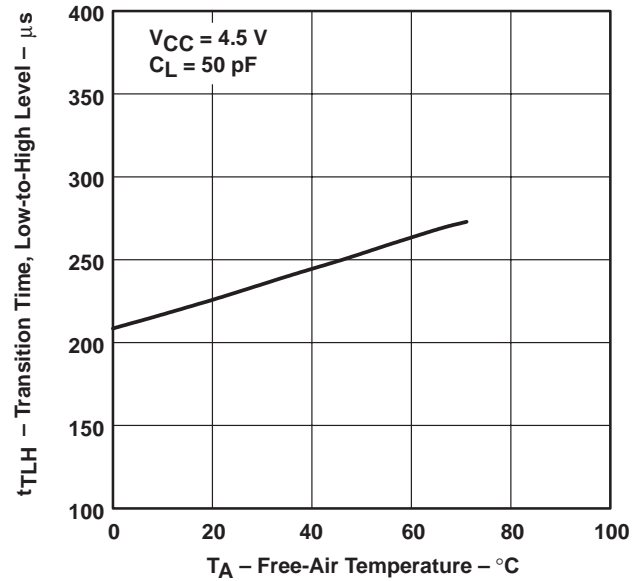


Figure 22

TRANSITION TIME,
 HIGH-TO-LOW-LEVEL OUTPUT
 vs
 FREE-AIR TEMPERATURE

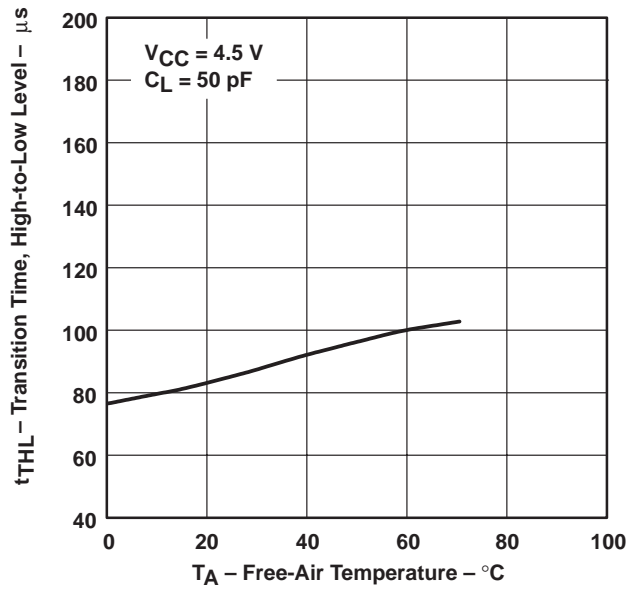


Figure 23

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